Product Name:

Determination of Energy Band Gap In Semiconductor

Product Code:

EEN0023



Description:

Determination of Energy Band Gap In Semiconductor

Technical Specification:

Determination of Energy Band Gap In Semiconductor

- To draw the characteristics of a P-N junction diode for reverse saturation current and temperature.
- To determine the energy band gap in a P-N junction diode.

Features:

The board consists of the following built-in parts:

- 01. 2V D.C. at 10mA, regulated power supply.
- 02. Digital microammeter, 3½ digits having range 200mA D.C.
- 03. Semiconductor diode.
- 04. Thermometer 0-110 °C.
- 05. Oven, electrically heated to heat the semiconductor diode.
- 06. Mains ON/OFF switch and fuse

Civil Mechanical India

Website: www.civilmechanicalindia.com, **Email:** export@civilmechanicalindia.com **Address:** 6148/6, Guru Nanak Marg, Ambala Cantt, Haryana, India, **Phone:** +91-0171-2643080, +91-0171-2601773